#### **SPECIFICATION** T60404-N4646-X460 Item no.: Date: 24.01.2022 K-no.: 24619 50 A Current Sensor for 5V- Supply Voltage For electronic current measurement: DC, AC, pulsed, mixed ..., with a galvanic isolation between primary circuit (short power) and secondary circuit (electronic circuit) Customers Part no.: Page 1 of Customer: Standard type Characteristics Description **Applications** Excellent accuracy Mainly used for stationary operation in industrial Closed loop (compensation) applications: Current Sensor with magnetic Very low offset current AC variable speed drives and servo motor field probe Very low temperature dependency and offset Printed circuit board mounting current drift Static converters for DC motor drives Casing and materials UL-listed Very low hysteresis of offset current Short response time Battery supplied applications Switched Mode Power Supplies (SMPS) Wide frequency bandwidth Compact design Power Supplies for welding applications Uninterruptible Power Supplies (UPS) Reduced offset ripple **Electrical data - Ratings** Primary nominal r.m.s. current 50 IPN $V_{out}$ Output voltage @ IP $V_{Ref} \pm (0.625*I_P/I_{PN})$ ٧ Output voltage @ IP=0, TA=25°C V<sub>Ref</sub> ± 0.0025 Vout External Reference voltage range $V_{Ref}$ 0...4 Internal Reference voltage 2.5 ±0.005 V $K_N$ Turns ratio 1...3:1400 Accuracy - Dynamic performance data min. typ. max. Unit

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V<sub>AC</sub>

600

I <sub>P,max</sub>	Max. measuring range	±150			
Х	Accuracy @ I <sub>PN</sub> , T <sub>A</sub> = 25°C			0.7	%
$\epsilon_{L}$	Linearity			0.1	%
V <sub>out</sub> - V <sub>Ref</sub>	Offset voltage @ I <sub>P</sub> =0, T <sub>A</sub> = 25°C			±2.5	mV
$\Delta$ V <sub>o</sub> / V <sub>Ref</sub> / $\Delta$ V	Temperature drift of Vout@ IP=0, TA= -4085°C		3	10	ppm/°C
t <sub>r</sub>	Response time @ 90% von I <sub>PN</sub>		500		ns
Δt (I <sub>P,max</sub> )	Delay time at di/dt = 100 A/μs		500		ns
f	Frequency bandwidth	DC100			kHz
General data					
		min.	typ.	max.	Unit
TA	Ambient operating temperature	-40		+85	°C
Ts	Ambient storage temperature	-40		+85	°C

Ts	Ambient storage to	-40		+85	°C	
m	Mass			15		g
Vc	Supply voltage		4.75	5	5.25	V
Ic	Current consumpt	ion		16		mA
		nanufactored and tested in acco ion, Insulation material group 1,			1 (Pin 1 - 6 to Pin	7 – 10)
Sclear	Clearance (compor	nent without solder pad)	10.2			mm
Screep	Creepage (compon	ent without solder pad)	10.2			mm
V <sub>sys</sub>	System voltage	overvoltage category 3	RMS		600	V
Vwork	Working voltage	(table 7 acc. to EN61800-5-1) overvoltage category 2	RMS		1020	V
U <sub>PD</sub>	Rated discharge v	oltage	peak value		1400	V

Date	Name	Issue	Amendment	umendment						
24.01.2022	NSch.	83	Applicable do	opplicable documents changed on sheet 3. "The color of the plastic material added. Minor change.						
15.05.14	DJ	83	Marking chan	Marking changed from 4646X460 → 4646-X460. CN-14-009						
Hrsg.: KB-E Bearb: DJ designer				KB-PM: KRe.			freig.: SB released			

**RMS** 

Max. potential difference acc. to UL 508



# **SPECIFICATION**

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Connections:

1...6: Ø 1.5 mm

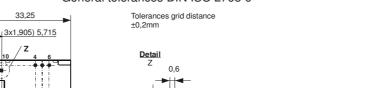
7..10: 0.7\*0.6 mm

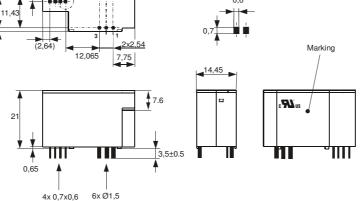
Customer: Standard type Mechanical outline (mm):

1.905

# General tolerances DIN ISO 2768-c

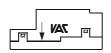
Customers Part no.:





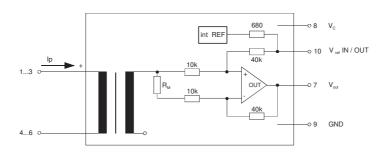
UL-sign 4646-X460 DC

Marking:



DC = Date Code F= Factory

### Schematic diagram



#### Possibilities of wiring $(@ T_A = 85^{\circ}C)$

primary windings	primary RMS	y current maximal	output voltage RMS	turns ratio	primary resistance	wiring
N <sub>P</sub>	I <sub>P</sub> [A]	Î <sub>P,max</sub> [A]	$V_{out}(I_P)[V]$	$K_N$	$R_P$ [m $\Omega$ ]	
1	50	±150	2.5±0.625	1:1400	0.1	1 3 6 4
2	25	±75	2.5±0.625	2:1400	0.45	3 6 4
3	16,7	±50	2.5±0.625	3:1400	1	1 3 4 4 A

Hrsg.: KB-E	Bearb: DJ	KB-PM: KRe.		freig.: SB
editor	designer	check		released

VACUUMSCHMELZE	SPECIFICATION		Item no.:	T60404-N4646-X460
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Customer: Standard type		Customers Part r	10.:	Page 3 of 4
		<u> </u>		

#### **Electrical Data**

		min.	typ.	max.	Unit
V <sub>Ctot</sub>	Maximum supply voltage (without function)			6	V
Ic	Supply Current with primary current	16m	$1A + I_p * K_N + V_0$	ut/RL	mA
I <sub>out,SC</sub>	Short circuit output current		±20		mA
$R_P$	Resistance / primary winding @ T <sub>A</sub> =25°C			0.3	$m\Omega$
Rs	Secondary coil resistance @ T <sub>A</sub> =85°C			30	Ω
$R_{i,Ref}$	Internal resistance of Reference input		670		Ω
$R_{i}$ ,( $V_{out}$ )	Output resistance of Vout			1	Ω
RL	External recommended resistance of Vout	1			$k\Omega$
CL	External recommended capacitance of Vout			500	pF
$\Delta X_{Ti}  /  \Delta V$	Temperature drift of X@T <sub>A</sub> = -40 +85 °C			40	ppm/K
$\Delta V_0 = \Delta (V_{out} - V_{Ref})$	Sum of any offset drift including:		2	6	mV
$V_{0t}$	Longtermdrift of V <sub>0</sub>		1		mV
V <sub>0T</sub>	Temperature drift von V <sub>0</sub> @ T <sub>A</sub> = -40+85°C		1		mV
$V_{0H}$	Hystereses of $V_{out} @ I_{P}=0$ (after an overload of 10 x $I_{P}$ )	۷)		1	mV
$\Delta V_0/\Delta V_C$	Supply voltage rejection ratio			1	mV/V
Voss	Offsetripple (with 1 MHz- filter first order)			22	mV
Voss	Offsetripple (with 100 kHz- filter firdt order)		3	8	mV
Voss	Offsetripple (with 20 kHz- filter first order)		0.6	1.5	mV
Ck	Maximum possible coupling capacity (primary – sec	condary)	5		pF
	Mechanical stress according to M3209/3 Settings: 10 – 2000 Hz, 1 min/Octave, 2 hours			30g	

## <u>Inspection</u> (Measurement after temperature balance of the samples at room temperature)

$V_{out}(I_P=I_{PN})$	(V)	M3011/6:	Output voltage vs. reference (I <sub>P</sub> =3x10As, 40-80Hz)	625±0,7%	mV
$V_{out}$ - $V_{Ref}$ (Ip=0	) (V)	M3226:	Offset voltage	± 0.0025	V
$V_d$	(V)	M3014:	Test voltage, rms, 1 s pin 1 – 6 vs. pin 7 – 10	2.5	kV
V <sub>e</sub>	(AQ	L 1/S4)	Partial discharge voltage acc.M3024 (RMS) with V <sub>vor</sub> (RMS)	1500 1875	V

## **Type Testing** (Pin 1 - 6 to Pin 7 - 10)

Vw	HV transient test according to M3064 (1,2 μs / 50 μs-wave form)	8	kV
$V_d$	Testing voltage to M3014 (5 s)	5	kV
Ve	Partial discharge voltage acc.M3024 (RMS)	1500	V
	with V <sub>vor</sub> (RMS)	1875	V

#### **Applicable documents**

Current direction: A positive output current appears at point  $V_{out}$ , by primary current in direction of the arrow. Further standards UL 508; file E317483, category NMTR2 / NMTR8

Enclosures according to IEC529: IP50.

Temperature of the primary conductor should not exceed 100°C

"The color of the plastic material is not specified and the current sensor can be supplied in different colors (e.g. brown, black, white, natural). This has no effect on the specifications or UL approval."

Hrsg.: KB-E	Bearb: DJ	KB-PM: KRe.		freig.: SB
editor	designer	check		released



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#### Explanation of sever al of the terms used in the tablets (in alphabetical order)

tr: Response time (describe the dynamic performance for the specified measurement range), measured as delay time at  $I_P = 0.9 \cdot I_{PN}$  between a rectangular current and the output voltage  $V_{OUt}$  ( $I_D$ )

Δt (I<sub>Pmax</sub>): Delay time (describe the dynamic performance for the rapid current pulse rate e.g short circuit current) measured between I<sub>Pmax</sub> and the output voltage V<sub>out</sub>(I<sub>Pmax</sub>) with a primary current rise of dip/dt ≥ 100 A/μs.

 $U_{PD}$  Rated discharge voltage (recurring peak voltage separated by the insulation) proved with a sinusoidal voltage  $V_e$   $U_{PD}$  =  $\sqrt{2} * V_e / 1.5$ 

V<sub>vor</sub> Defined voltage is the RMS valve of a sinusoidal voltage with peak value of 1,875 \* U<sub>PD</sub> required for partial discharge test in IEC 61800-5-1

 $V_{vor} = 1.875 * U_{PD} / \sqrt{2}$ 

V<sub>sys</sub> System voltage RMS value of rated voltage according to IEC 61800-5-1

Vwork Working voltage voltage according to IEC 61800-5-1 which occurs by design in a circuit or across insulation

 $V_0$ : Offset voltage between  $V_{out}$  and the rated reference voltage of  $V_{ref} = 2,5V$ .

 $V_0 = V_{out}(0) - 2,5V$ 

V<sub>0H</sub>: Zero variation of V<sub>0</sub> after overloading with a DC of tenfold the rated value

 $V_{0t}$ : Long term drift of  $V_0$  after 100 temperature cycles in the range -40 bis 85 °C.

X: Permissible measurement error in the final inspection at RT, defined by

 $X = 100 \cdot \left| \frac{V_{out}(I_{PN}) - V_{out}(0)}{0.625V} - 1 \right| \%$ 

X<sub>ges</sub>(I<sub>PN</sub>): Permissible measurement error including any drifts over the temperature range by the current measurement I<sub>PN</sub>

 $X_{ges} = 100 \cdot \left| \frac{V_{out}(I_{PN}) - 2,5V}{0,625V} - 1 \right| \% \text{ or } X_{ges} = 100 \cdot \left| \frac{V_{out}(I_{PN}) - V_{ref}}{0,625V} - 1 \right| \%$ 

 $\varepsilon_{\rm L} = 100 \cdot \left| \frac{\rm I_P}{\rm I_{PN}} - \frac{\rm V_{\it out}(I_{\it P}) - V_{\it out}(0)}{\rm V_{\it out}(I_{\it PN}) - V_{\it out}(0)}} \right| \%$